

Supporting Information

Pd-Zn Nanocrystals for High-Efficient Formic Acid Oxidation

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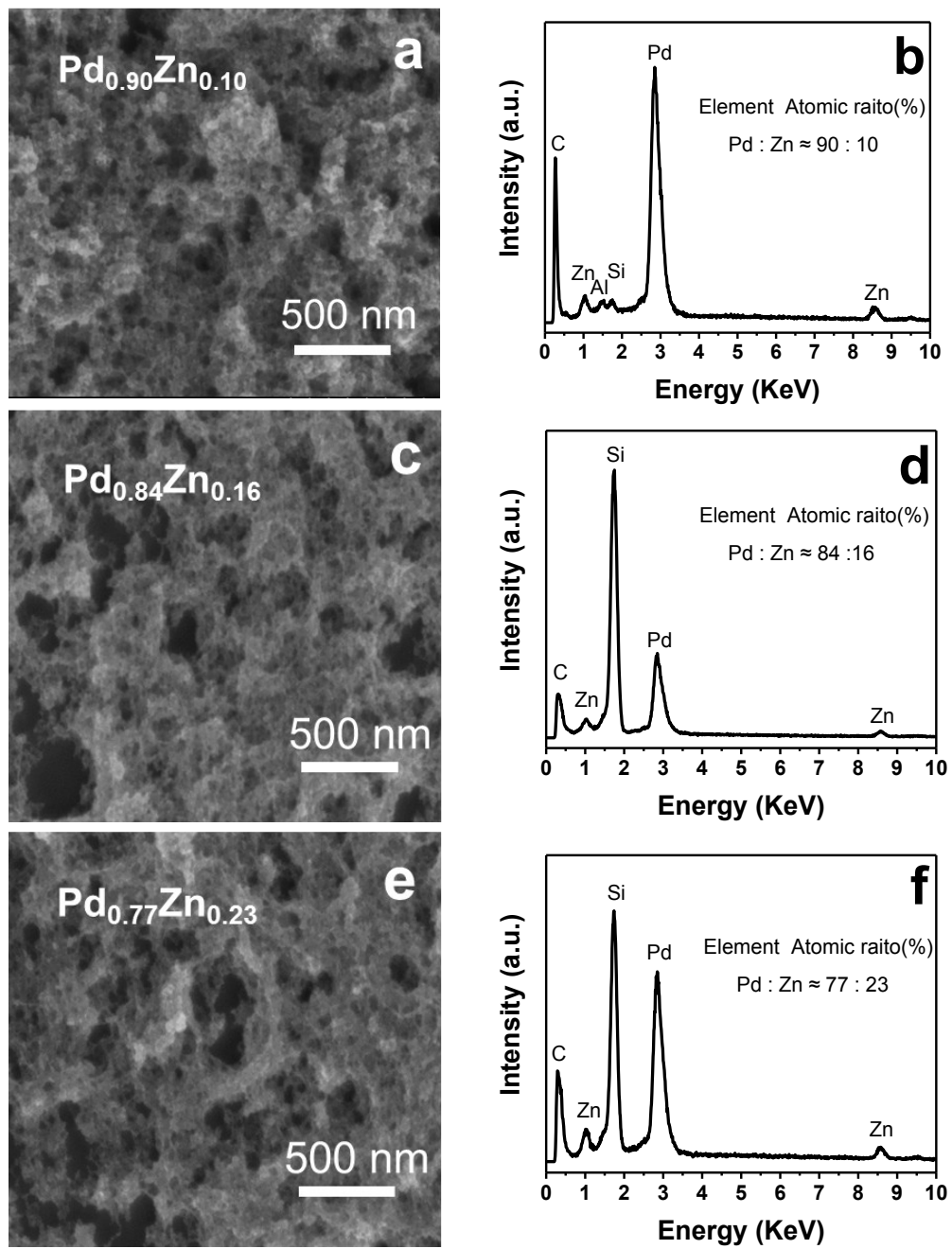


Fig. S1 SEM images and EDS spectral of the series of $\text{Pd}_x\text{Zn}_{1-x}$ NCs, (a) and (b) $\text{Pd}_{0.90}\text{Zn}_{0.10}$, (c) and (d) $\text{Pd}_{0.84}\text{Zn}_{0.16}$, (e) and (f) $\text{Pd}_{0.77}\text{Zn}_{0.23}$.

Table S1 Pd/Zn Atomic Ratios (%) for the series of Pd_xZn_{1-x} NCs determined by ICP-MS and EDS.

samples	Pd_{0.90}Zn_{0.10}	Pd_{0.84}Zn_{0.16}	Pd_{0.77}Zn_{0.23}
ICP-MS	89.7/10.3	83.7/16.3	76.8/23.2
EDS	90.1/9.9	82.81/17.9	77.5/22.5

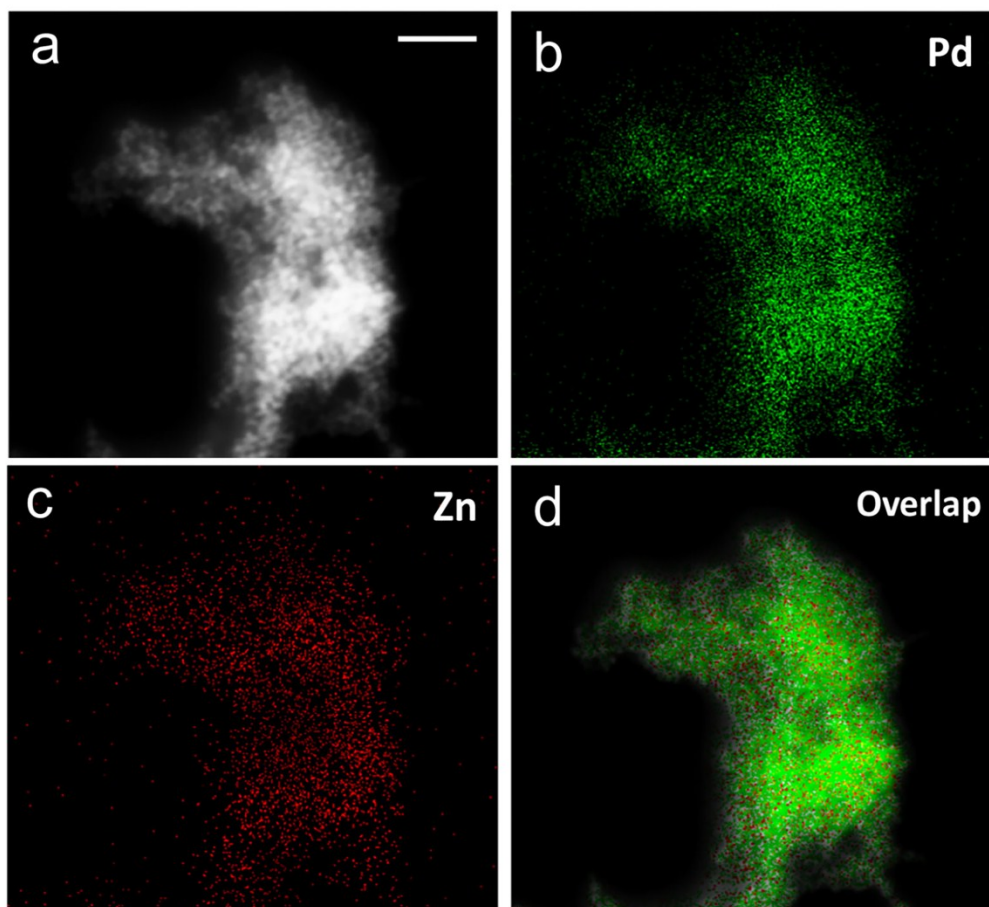


Fig. S2 (a) HAADF-STEM image of $\text{Pd}_{0.90}\text{Zn}_{0.10}$, (b) Pd mapping in green, (c) Zn mapping in red, and (d) Overlapped mapping of Pd and Zn. Scale bar: 200 nm.

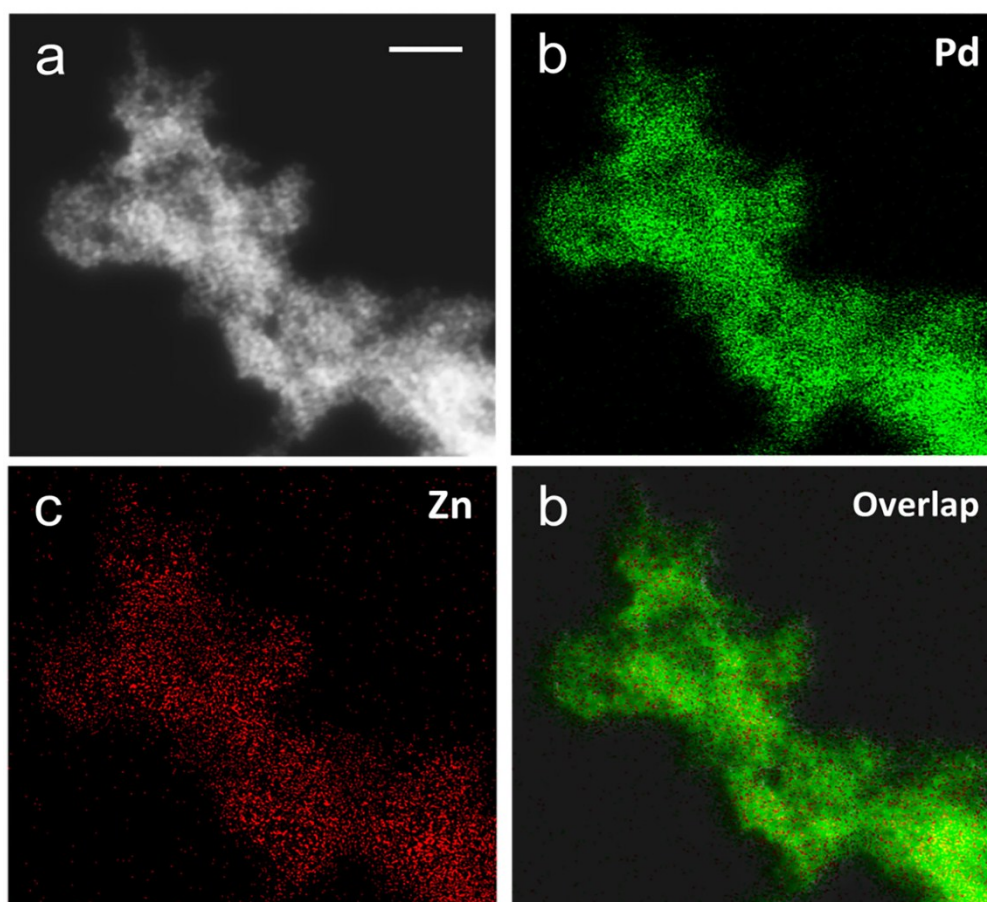


Fig. S3 (a) HAADF-STEM image of Pd_{0.84}Zn_{0.16}, (b) Pd mapping in green, (c) Zn mapping in red, and (d) overlapped mapping of Pd and Zn. Scale bar: 200 nm.

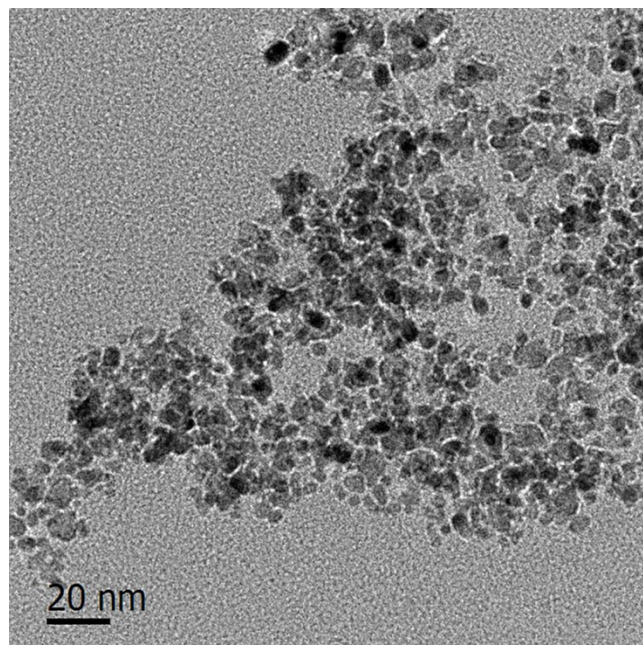


Fig. S4 TEM image of the irregularity Pd NCs which were synthesized in the absence of Zn precursor.

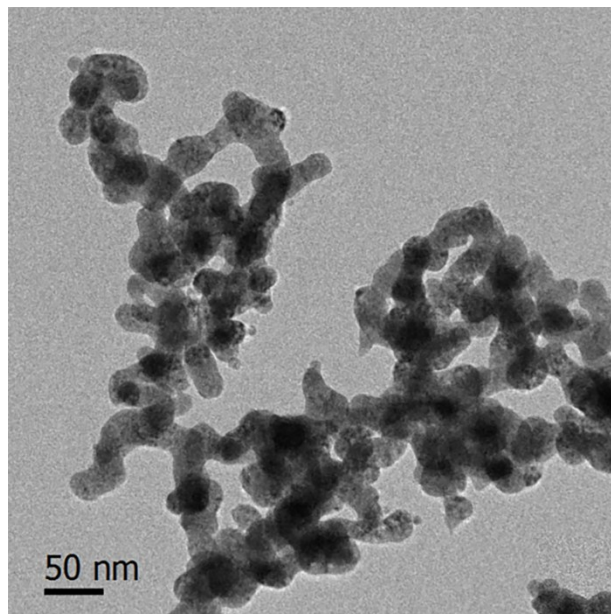


Fig. S5 TEM image of Pd_{0.77}Zn_{0.23} NCs alloy which was synthesized in the absence of DMF.

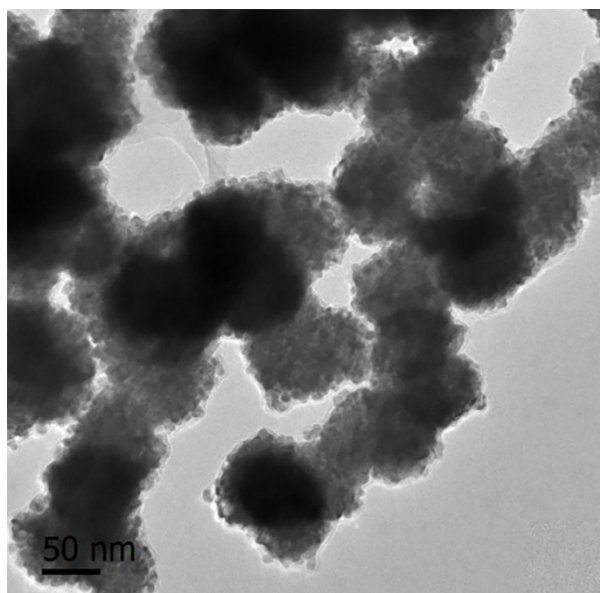


Fig. S6 TEM image of Pd_{0.77}Zn_{0.23} NCs alloy which was synthesized in the absence of PVP.

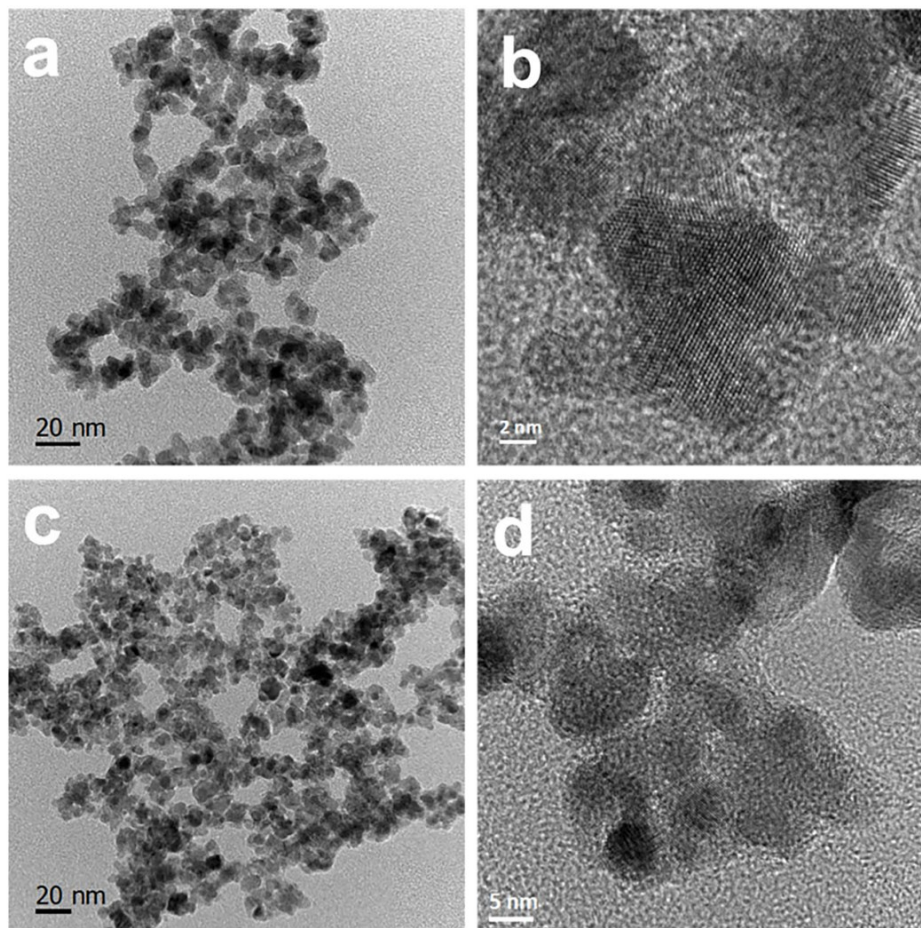


Fig. S7 The representative TEM images of $\text{Pd}_{0.77}\text{Zn}_{0.23}$ NCs obtained with different precursor species.

Replacing ZnCl_2 with (a-b) $\text{Zn}(\text{NO}_3)_2$ and (c-d) $\text{Zn}(\text{acac})_2$.

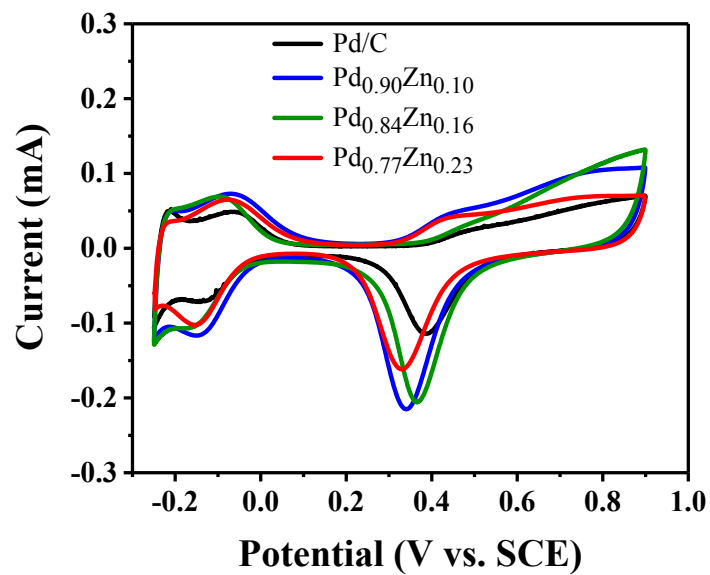


Fig. S8 CV of the Pd_xZn_{1-x} NCs and Pd/C catalyst in Ar-saturated in 0.1 M HClO₄ at a scan rate of 50 mV s⁻¹.

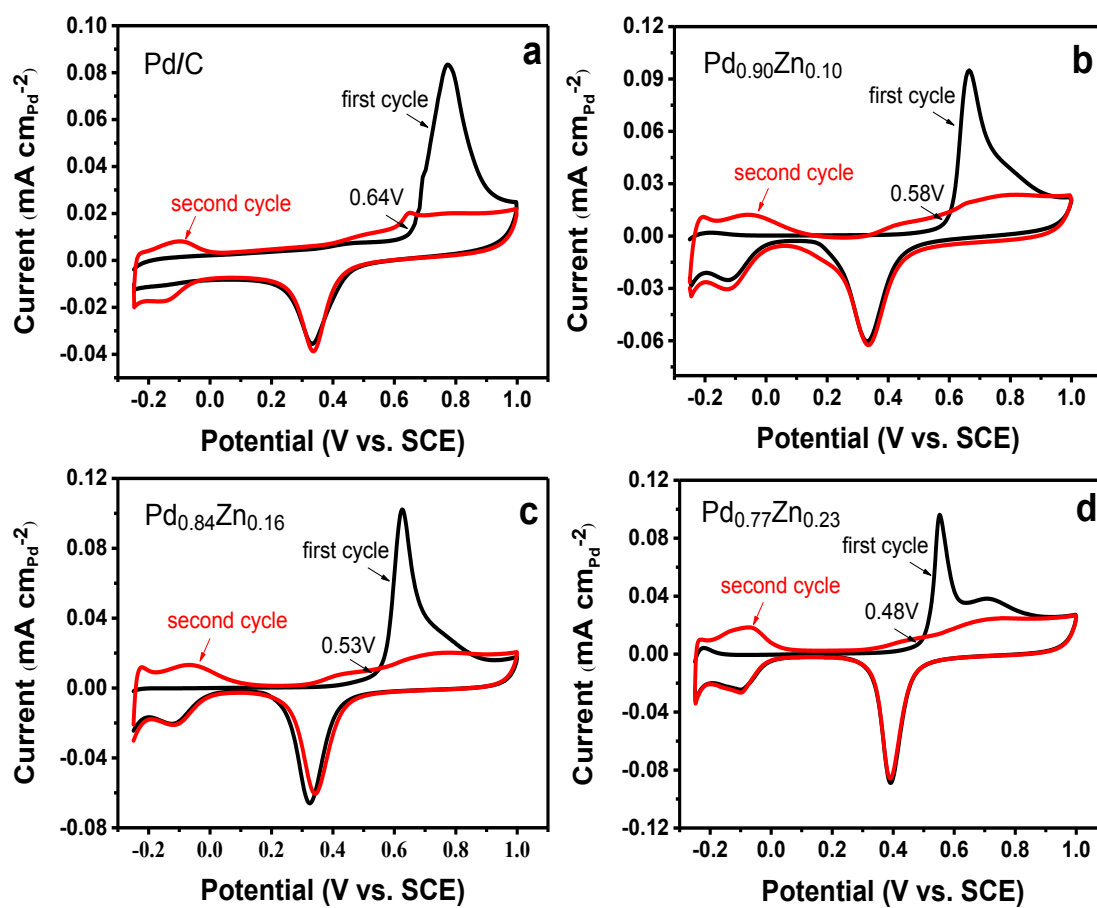


Fig. S9 CO stripping voltammograms of (a) Pd/C, (b) Pd_{0.90}Zn_{0.10}, (c) Pd_{0.84}Zn_{0.16} and (d) Pd_{0.77}Zn_{0.23} NCs in 0.1 M HClO₄ at a scan rate of 20 mV s⁻¹.

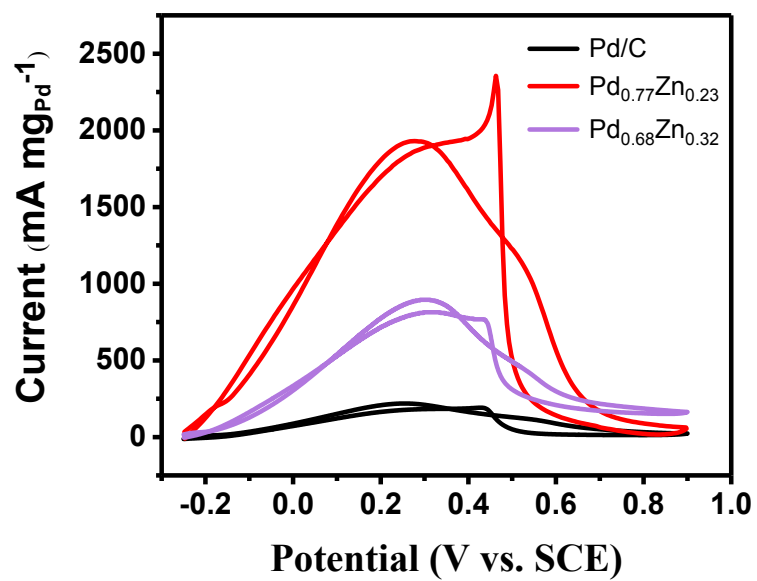


Fig. S10 CV curves of Pd_{0.68}Zn_{0.32} and Pd/C catalyst in 0.1 M HClO₄ and 0.5 M HCOOH at a scan rate of 50 mV s⁻¹.

Table S2 Formic acid oxidation behavior on various Pd or Pd-based electrocatalysts is to compare it to Pd-Zn NCs catalysts.

Catalysts	Test condition	specific activity (mA cm _{Pd} ⁻²)	Mass activity (mA mg _{Pd} ⁻²)	CO-stripping onset potential (V)	Ref
Pd_{0.77}Zn_{0.23}	0.1 M HClO₄ and 0.5 M HCOOH	13.5	1945.0	0.48	this
Pd bipyramids	0.5 M HClO ₄ and 0.5 M HCOOH	20.8	/	/	1
Pd ₃ Pt Half-Shells	0.5 M HClO ₄ and 0.5 M HCOOH	/	318.0	0.63	2
np-Pd ₅₀ Cu ₅₀	0.1 M HClO ₄ and 0.1 M HCOOH	6.40	640.5	0.68	3
Cu-Pd multipods	0.1 M HClO ₄ and 1 M HCOOH	2.14	/	0.89	4
Pd nanochains	0.5 M H ₂ SO ₄ and 0.5 M HCOOH	40.2	283.8	0.80	5
CuPd@Pd tetrahedra	0.5 M H ₂ SO ₄ and 0.5 M HCOOH	4.93	501.8	0.52	6
PdNiCu/C	0.5 M H ₂ SO ₄ and 0.5 M HCOOH	3.30	792.0	0.70	7
ordered Pd ₃ Fe/C	0.5 M H ₂ SO ₄ and 0.5 M HCOOH	/	696.4	/	8
Pd-Cu Tripods	0.5 M HClO ₄ and 0.5 M HCOOH	5.81	1580.0	/	9
Pd-Cu network	0.5 M H ₂ SO ₄ and 0.5 M HCOOH	1.50	517.0	/	10
PdNi nanowire	0.5 M H ₂ SO ₄ and 0.5 M HCOOH	/	604.3	/	11

Pd-Ni-P	0.5 M H ₂ SO ₄ and 0.5 M HCOOH	/	1457.0	/	12
Pd-Fe/RGO	0.1 M H ₂ SO ₄ and 0.5 M HCOOH	2.71	1000.0	/	13
Pd ₄ Ni/rGO	0.5 M H ₂ SO ₄ and 0.5 M HCOOH	/	1435.0	/	14
Pd-Mo ₂ N/rGO	0.5 M H ₂ SO ₄ and 0.5 M HCOOH	1.03	532.7	0.82	15
PdO/Pd-CeO ₂ hollow sphere	0.5 M H ₂ SO ₄ and 0.5 M HCOOH	/	1620.0	0.69	16
PdAu/rGO	0.5 M H ₂ SO ₄ and 0.5 M HCOOH	3.67	2040.0	0.68	17

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